

Standard Rectifier Module

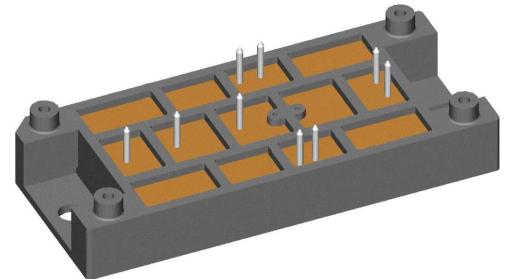
PHASE OUT

3~ Rectifier Bridge + NTC

| |
|---------------------------|
| 3~ Rectifier |
| $V_{RRM} = 1200\text{ V}$ |
| $I_{DAV} = 180\text{ A}$ |
| $I_{FSM} = 1100\text{ A}$ |

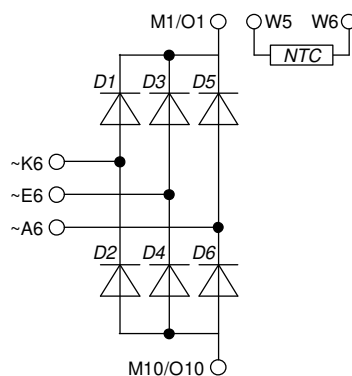
Part number

VUO120-12NO2T



Backside: isolated

 E72873



Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current
- NTC

Applications:

- Diode for main rectification
- For three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: V2-Pack

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Height: 17 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Recommended replacement: VUO121-16NO1; MDMA120U1600VA

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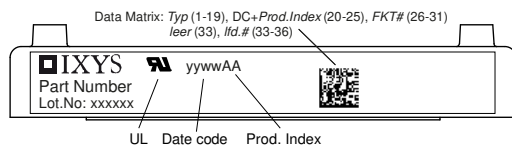


| Rectifier | | | | Ratings | | | |
|------------|--|---|---|--------------------------|------|------|-------------------|
| Symbol | Definition | Conditions | | min. | typ. | max. | Unit |
| V_{RSM} | max. non-repetitive reverse blocking voltage | | | | | 1300 | V |
| V_{RRM} | max. repetitive reverse blocking voltage | | | | | 1200 | V |
| I_R | reverse current | $V_R = 1200$ V | $T_{VJ} = 25^\circ\text{C}$ | | | 100 | μA |
| | | $V_R = 1200$ V | $T_{VJ} = 125^\circ\text{C}$ | | | 2 | mA |
| V_F | forward voltage drop | $I_F = 60$ A | $T_{VJ} = 25^\circ\text{C}$ | | | 1.16 | V |
| | | $I_F = 180$ A | | | | 1.55 | V |
| | | $I_F = 60$ A | $T_{VJ} = 125^\circ\text{C}$ | | | 1.09 | V |
| | | $I_F = 180$ A | | | | 1.59 | V |
| I_{DAV} | bridge output current | $T_C = 90^\circ\text{C}$ rectangular | $T_{VJ} = 150^\circ\text{C}$ $d = \frac{1}{3}$ | | | 180 | A |
| V_{FO} | threshold voltage | } for power loss calculation only | | | | 0.81 | V |
| r_F | slope resistance | | | | | 4.4 | m Ω |
| R_{thJC} | thermal resistance junction to case | | | | | 0.6 | K/W |
| R_{thCH} | thermal resistance case to heatsink | | | | 0.2 | | K/W |
| P_{tot} | total power dissipation | | | $T_C = 25^\circ\text{C}$ | | 205 | W |
| I_{FSM} | max. forward surge current | $t = 10$ ms; (50 Hz), sine | $T_{VJ} = 45^\circ\text{C}$ | | | 1.10 | kA |
| | | $t = 8,3$ ms; (60 Hz), sine | $V_R = 0$ V | | | 1.19 | kA |
| | | $t = 10$ ms; (50 Hz), sine | $T_{VJ} = 150^\circ\text{C}$ | | | 935 | A |
| | | $t = 8,3$ ms; (60 Hz), sine | $V_R = 0$ V | | | 1.01 | kA |
| I^2t | value for fusing | $t = 10$ ms; (50 Hz), sine | $T_{VJ} = 45^\circ\text{C}$ | | | 6.05 | kA ² s |
| | | $t = 8,3$ ms; (60 Hz), sine | $V_R = 0$ V | | | 5.89 | kA ² s |
| | | $t = 10$ ms; (50 Hz), sine | $T_{VJ} = 150^\circ\text{C}$ | | | 4.37 | kA ² s |
| | | $t = 8,3$ ms; (60 Hz), sine | $V_R = 0$ V | | | 4.25 | kA ² s |
| C_J | junction capacitance | $V_R = 400$ V; $f = 1$ MHz | $T_{VJ} = 25^\circ\text{C}$ | | 37 | | pF |

PHASE OUT



| Package V2-Pack | | Ratings | | | | |
|-----------------|--|---|------|------|------|------|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
| I_{RMS} | RMS current | per terminal | | | 100 | A |
| T_{VJ} | virtual junction temperature | | -40 | | 150 | °C |
| T_{op} | operation temperature | | -40 | | 125 | °C |
| T_{stg} | storage temperature | | -40 | | 125 | °C |
| Weight | | | | 76 | | g |
| M_D | mounting torque | | 2 | | 2.5 | Nm |
| $d_{Spp/App}$ | creepage distance on surface / striking distance through air | terminal to terminal | 6.0 | | | mm |
| $d_{Spb/Apb}$ | | terminal to backside | 12.0 | | | mm |
| V_{ISOL} | isolation voltage | t = 1 second 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA | 3600 | | | V |
| | | t = 1 minute | 3000 | | | V |



| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | VUO120-12NO2T | VUO120-12NO2T | Box | 6 | 510989 |

| Similar Part | Package | Voltage class |
|---------------|---------|---------------|
| VUO120-16NO2T | V2-Pack | 1600 |

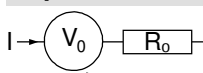
Temperature Sensor NTC

| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
|-------------|-------------------------|---------------------|------|------|------|------------|
| R_{25} | resistance | $T_{VJ} = 25^\circ$ | 4.75 | 5 | 5.25 | k Ω |
| $B_{25/50}$ | temperature coefficient | | | 3375 | | K |

Equivalent Circuits for Simulation

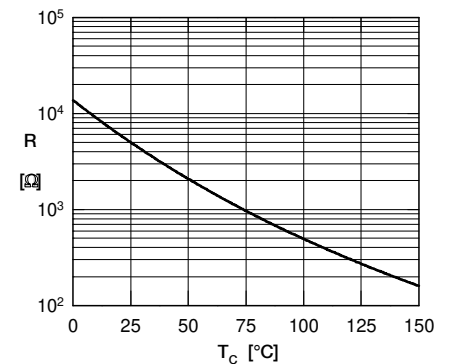
* on die level

$T_{VJ} = 150^\circ\text{C}$



Rectifier

| | | | | | | |
|--------------|--------------------|------|--|--|--|------------|
| $V_{0\ max}$ | threshold voltage | 0.81 | | | | V |
| $R_{0\ max}$ | slope resistance * | 3.2 | | | | m Ω |



Typ. NTC resistance vs. temperature

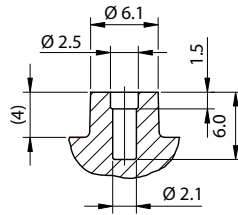


Outlines V2-Pack

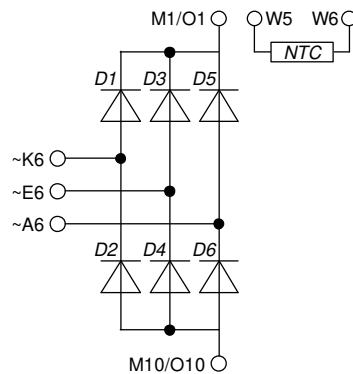
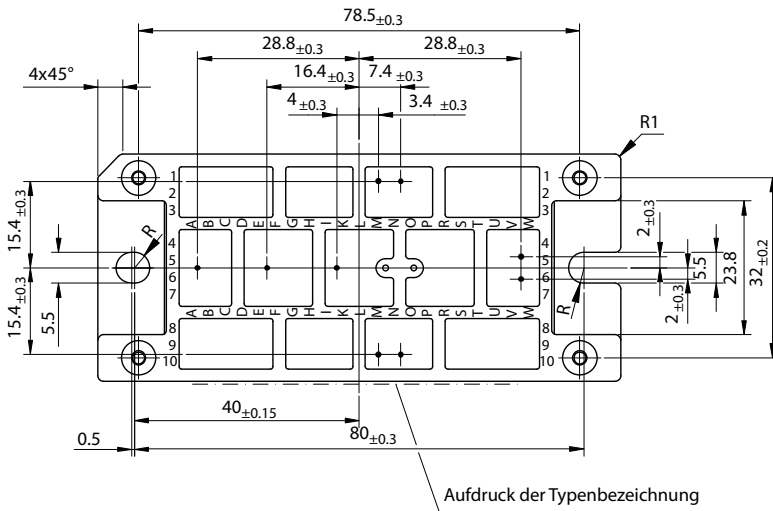
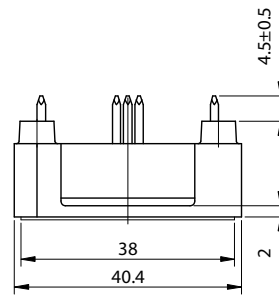
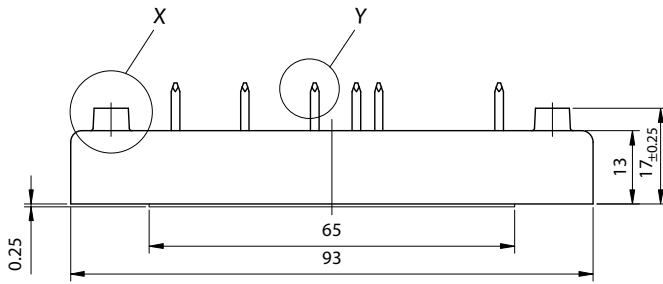
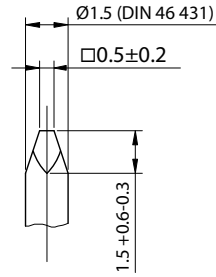
Remarks:

EJOT PT® self-tapping screws of the dimension K25 are recommended for the mechanical connection between module and PCB. Choose the right length according to your board thickness at a maximum depth of 6 mm of the module holes.¹ The recommended mounting torque is 1.5 Nm.

Detail X M2:1



Detail Y M5:1



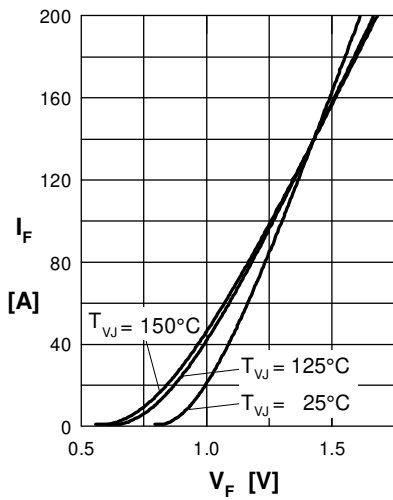
Rectifier


Fig. 1 Forward current vs. voltage drop per diode

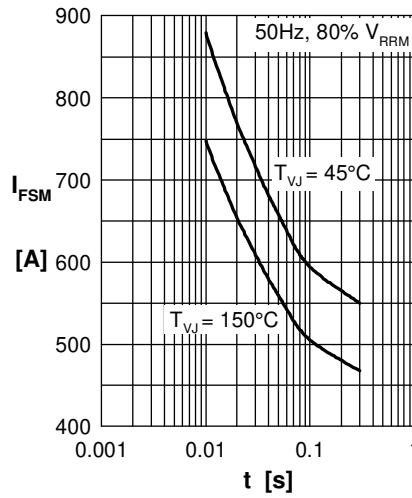


Fig. 2 Surge overload current vs. time per diode

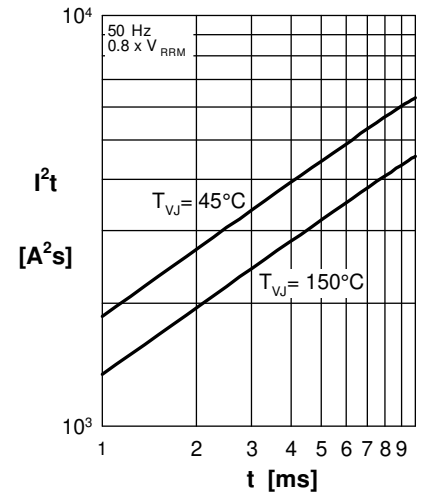
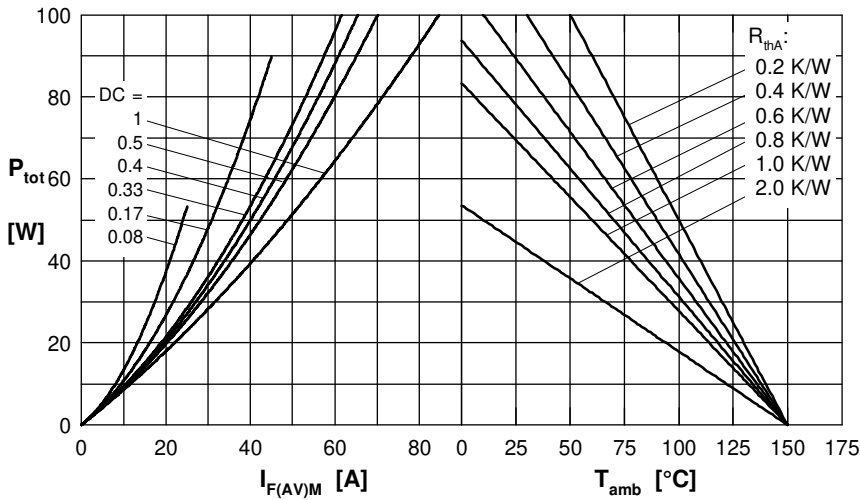

 Fig. 3 I^2t vs. time per diode


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

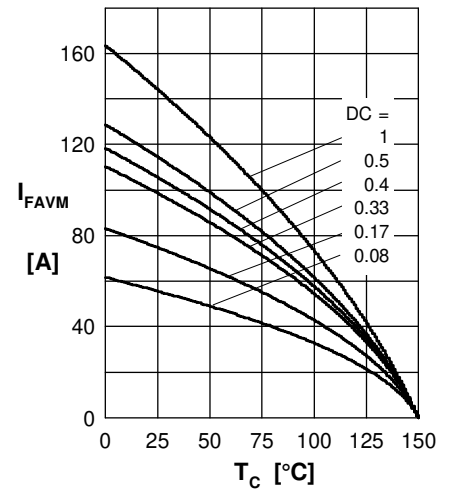


Fig. 5 Max. forward current vs. case temperature per diode

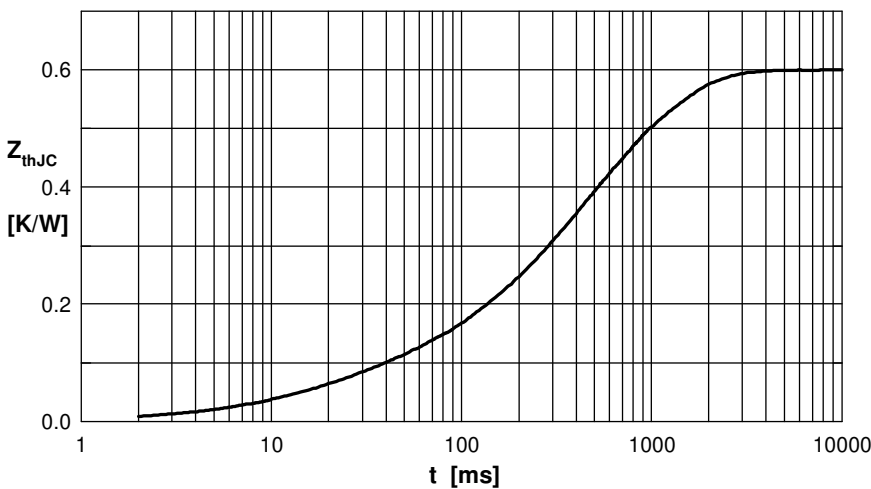


Fig. 6 Transient thermal impedance junction to case vs. time per diode

| R_i | t_i |
|-------|-------|
| 0.060 | 0.020 |
| 0.003 | 0.010 |
| 0.150 | 0.225 |
| 0.243 | 0.800 |
| 0.144 | 0.580 |



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

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- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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